MA MOSPEC

Surface Mount Ultrafast Power Rectifiers

Ideally suited for high voltage, high frequency rectification, or as free wheeling and protection diodes in surface mount applications where compact size and weight are critical to the system.

- * Low Power Loss, High efficiency
- * Glass Passivated chips junction
- * 150 °C Operating Junction Temperature

- * Low Stored Charge Majority Carrier Conduction

 * Low Forward Voltage Drop , High Current Capability

 * High-Switching Speed 35 & 50 Nanosecond Recovery Time
- * Small Compact Surface Mountable Package with J-Bend Lead
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

MAXIMUM RATINGS

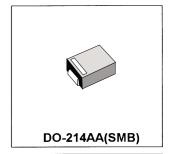
Characteristic	Symbol	ми						Unit
		51	52	53	54	55	56	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	150	200	300	400	٧
RMS Reverse Voltage	V _{R(RMS)}	35	70	105	140	210	280	٧
Average Rectifier Forward Current	I _o	5.0					Α	
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware,single phase,60Hz)	I _{FSM}	100 75			5	А		
Operating and Storage Junction Temperature Range	T _j , T _{stg}	- 65 to + 150				°C		

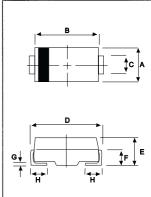
FLECTRICAL CHARACTERISTICS

Characteristic	Symbol	MU						Unit
		51	52	53	54	55	56	
Maximum Instantaneous Forward Voltage $(I_E = 5.0 \text{ Amp}, T_C = 25 ^{\circ}\text{C})$	V _F	1.00			1.30		٧	
Maximum Instantaneous Reverse Current	I _R						uA	
(Rated DC Voltage, T _c = 25 °C) (Rated DC Voltage, T _c = 125 °C)		5.0 70						
Reverse Recovery Time ($I_F = 0.5 \text{ A}$, $I_R = 1.0$, $I_{rr} = 0.25 \text{ A}$)	Т,,			35		5	50	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C _P		5	55		4	15	pF

ULTRA FAST RECTIFIERS

5.0 AMPERES 50 -- 400 VOLTS





DIM	MILLMETERS						
	MIN	MAX					
Α	3.30	3.90					
В	4.20	4.60					
C	1.80	2.20					
D	4.90	5.60					
E	1.90	2.50					
F		1.30					
G		0.22					
Н	0.85	1.45					

CASE---Transfer molded plastic

POLARITY---Cathode indicated polarity band

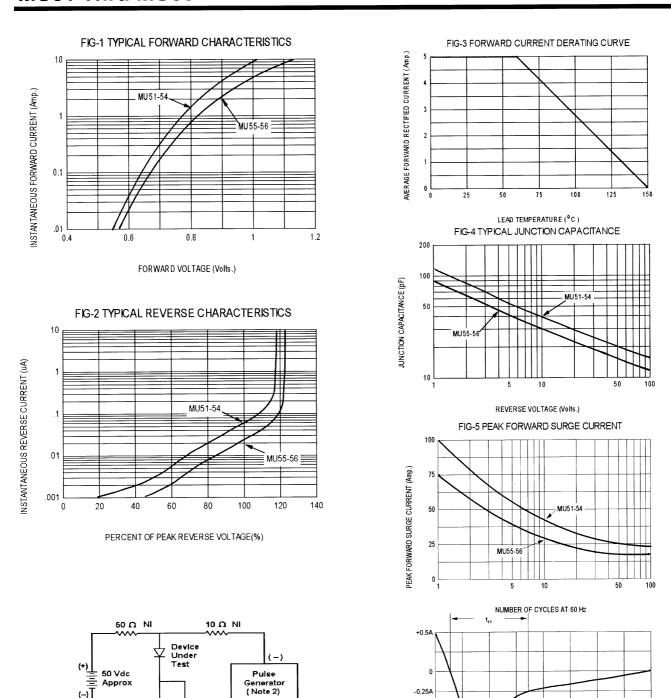


Fig-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

-1.0A

Set time base for 10/20 ns/div

(+)

1Ω

Ni

Notes: 1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

Oscilloscope (Note 1)



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